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LC²MOS 4-/8-Channel High Performance Analog Multiplexers

Data Sheet

ADG408/ADG409

FEATURES

- 44 V supply maximum ratings
- V_{SS} to V_{DD} analog signal range
- Low on resistance (100 Ω maximum)
- Low power (I_{SUPPLY} < 75 µA)
- Fast switching
- Break-before-make switching action
- Plug-in replacement for DG408/DG409

APPLICATIONS

- Audio and video routing
- Automatic test equipment
- Data acquisition systems
- Battery-powered systems
- Sample-and-hold systems
- Communication systems

FUNCTIONAL BLOCK DIAGRAMS

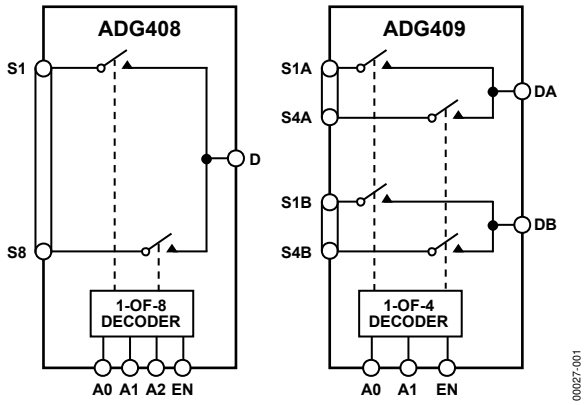

Figure 1.

GENERAL DESCRIPTION

The ADG408/ADG409 are monolithic CMOS analog multiplexers comprising eight single channels and four differential channels, respectively. The ADG408 switches one of eight inputs to a common output as determined by the 3-bit binary address lines A0, A1, and A2. The ADG409 switches one of four differential inputs to a common differential output, as determined by the 2-bit binary address lines A0 and A1. An EN input on both devices is used to enable or disable the device. When the device is disabled, all channels are switched off.

The ADG408/ADG409 are designed on an enhanced LC²MOS process that provides low power dissipation yet gives high switching speed and low on resistance. Each channel conducts equally well in both directions when on and has an input signal range that extends to the supplies. In the off condition, signal levels up to the supplies are blocked. All channels exhibit break-before-make switching action, preventing momentary shorting when switching channels. Inherent in the design is low charge injection for minimum transients when switching the digital inputs.

The ADG408/ADG409 are improved replacements for the DG408/DG409 analog multiplexers.

PRODUCT HIGHLIGHTS

1. Extended Signal Range. The ADG408/ADG409 are fabricated on an enhanced LC²MOS process, giving an increased signal range that extends to the supply rails.
2. Low Power Dissipation.
3. Low R_{ON}.
4. Single-Supply Operation. For applications where the analog signal is unipolar, the ADG408/ADG409 can be operated from a single rail power supply. The parts are fully specified with a single 12 V power supply and remain functional with single supplies as low as 5 V.

Rev. D

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
Tel: 781.329.4700
Technical Support www.analog.com

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3/03—Rev. A to Rev. B

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Updated Outline Dimensions 11

2/01—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

V_{DD} = 15 V, V_{SS} = −15 V, GND = 0 V, unless otherwise noted.

Table 1.

Parameter	B Version +25°C	B Version −40°C to +85°C	T Version +25°C	T Version −55°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH						
Analog Signal Range		V_{SS} to V_{DD}		V_{SS} to V_{DD}	V	
R_{ON}	40		40		Ω typ	V_D = ±10 V, I_S = −10 mA
	100	125	100	125	Ω max	
ΔR_{ON}	15		15		Ω max	V_D = +10 V, −10 V
LEAKAGE CURRENTS						
Source Off Leakage I_S (Off)	±0.5	±50	±0.5	±50	nA max	V_D = ±10 V, V_S = ∓10 V; see Figure 19
Drain Off Leakage I_D (Off)						V_D = ±10 V, V_S = ∓10 V; see Figure 20
ADG408	±1	±100	±1	±100	nA max	
ADG409	±1	±50	±1	±50	nA max	
Channel On Leakage I_D, I_S (On)						V_S = V_D = ±10 V; see Figure 21
ADG408	±1	±100	±1	±100	nA max	
ADG409	±1	±50	±1	±50	nA max	
DIGITAL INPUTS						
Input High Voltage, V_{INH}		2.4		2.4	V min	
Input Low Voltage, V_{INL}		0.8		0.8	V max	
Input Current						
I_{INL} or I_{INH}		±10		±10	μA max	V_{IN} = 0 or V_{DD}
C_{IN}, Digital Input Capacitance	8		8		pF typ	f = 1 MHz
DYNAMIC CHARACTERISTICS[1]						
$t_{TRANSITION}$		120		120	ns typ	R_L = 300 Ω, C_L = 35 pF;
		250		250	ns max	V_{S1} = ±10 V, V_{S8} = ∓10 V; see Figure 22
t_{OPEN}	10	10	10	10	ns min	R_L = 300 Ω, C_L = 35 pF;
						V_S = 5 V; see Figure 23
t_{ON} (EN)	85	125	85	125	ns typ	R_L = 300 Ω C_L = 35 pF;
	150	225	150	225	ns max	V_S = 5 V; see Figure 24
t_{OFF} (EN)		65		65	ns typ	R_L = 300 Ω, C_L = 35 pF;
		150		150	ns max	V_S = 5 V; see Figure 24
Charge Injection	20		20		pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 10 nF; see Figure 25
OFF Isolation	−75		−75		dB typ	R_L = 1 kΩ, f = 100 kHz;
						V_{EN} = 0 V; see Figure 26
Channel-to-Channel Crosstalk	85		85		dB typ	RL = 1 kΩ, f = 100 kHz; see Figure 27
C_S (OFF)	11		11		pF typ	f = 1 MHz
C_D (OFF)						f = 1 MHz
ADG408	40		40		pF typ	
ADG409	20		20		pF typ	
C_D, C_S (ON)						f = 1 MHz
ADG408	54		54		pF typ	
ADG409	34		34		pF typ	

Parameter	B Version +25°C	B Version −40°C to +85°C	T Version +25°C	T Version −55°C to +125°C	Unit	Test Conditions/Comments
POWER REQUIREMENTS						
I_{DD}		1		1	µA typ	V_{IN} = 0 V, V_{EN} = 0 V
		5		5	µA max	
I_{SS}		1		1	µA typ	
		5		5	µA max	
I_{DD}	100		100		µA typ	V_{IN} = 0 V, V_{EN} = 2.4 V
	200	500	200	500	µA max	

[1] Guaranteed by design, not subject to production test.

SINGLE SUPPLY

V_{DD} = 12 V, V_{SS} = 0 V, GND = 0 V, unless otherwise noted.

Table 2.

Parameter	B Version +25°C	B Version −40°C to +85°C	T Version +25°C	T Version −55°C to +125°C	Unit	Test Conditions/Comments
ANALOG SWITCH						
Analog Signal Range		0 to V_{DD}		0 to V_{DD}	V	
R_{ON}	90		90		Ω typ	V_D = 3 V, 10 V, I_S = −1 mA
LEAKAGE CURRENTS						
Source Off Leakage I_S (Off)	±0.5	±50	±0.5	±50	nA max	VD = 8 V/0 V, V_S = 0 V/8 V; see Figure 19
Drain Off Leakage I_D (Off)						V_D = 8 V/0 V, V_S = 0 V/8 V; see Figure 20
ADG408	±1	±100	±1	±100	nA max	
ADG409	±1	±50	±1	±50	nA max	
Channel On Leakage I_D, I_S (On)						V_S = V_D = 8 V/0 V; see Figure 21
ADG408	±1	±100	±1	±100	nA max	
ADG409	±1	±50	±1	±50	nA max	
DIGITAL INPUTS						
Input High Voltage, V_{INH}		2.4		2.4	V min	
Input Low Voltage, V_{INL}		0.8		0.8	V max	
Input Current						
I_{INL} or I_{INH}		±10		±10	µA max	V_{IN} = 0 or V_{DD}
C_{IN}, Digital Input Capacitance	8		8		pF typ	f = 1 MHz
DYNAMIC CHARACTERISTICS[1]						
$t_{TRANSITION}$	130		130		ns typ	R_L = 300 Ω, C_L = 35 pF; V_{S1} = 8 V/0 V, V_{S8} = 0 V/8 V; see Figure 22
t_{OPEN}	10		10		ns typ	R_L = 300 Ω, C_L = 35 pF; V_S = 5 V; see Figure 23
t_{ON} (EN)	140		140		ns typ	R_L = 300 Ω C_L = 35 pF; V_S = 5 V; see Figure 24
t_{OFF} (EN)	60		60		ns typ	R_L = 300 Ω, C_L = 35 pF; V_S = 5 V; see Figure 24
Charge Injection	5		5		pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 10 nF; see Figure 25
Off Isolation	−75		−75		dB typ	R_L = 1 kΩ f = 100 kHz; V_{EN} = 0 V; see Figure 26

Parameter	B Version		T Version		Unit	Test Conditions/Comments
	+25°C	−40°C to +85°C	+25°C	−55°C to +125°C		
Channel-to-Channel Crosstalk	85		85		dB typ	R_L = 1 kΩ, f = 100 kHz; see Figure 27
C_S (Offf)	11		11		pF typ	f = 1 MHz
C_D (Off)						f = 1 MHz
ADG408	40		40		pF typ	
ADG409	20		20		pF typ	
C_D, C_S (On)						f = 1 MHz
ADG408	54		54		pF typ	
ADG409	34		34		pF typ	
POWER REQUIREMENTS						
I_{DD}		1		1	µA typ	V_{IN} = 0 V, V_{EN} = 0 V
		5		5	µA max	
I_{DD}	100		100		µA typ	V_{IN} = 0 V, V_{EN} = 2.4 V
	200	500	200	500	µA max	

[1] Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

T_A = 25°C, unless otherwise noted.

Table 3.

Parameter	Rating
V_{DD} to V_{SS}	44 V
V_{DD} to GND	−0.3 V to +32 V
V_{SS} to GND	+0.3 V to −32 V
Analog, Digital Inputs	V_{SS} − 2 V to V_{DD} + 2 V or 20 mA, whichever occurs first
Continuous Current, S or D	20 mA
Peak Current, S or D	
(Pulsed at 1 ms, 10% Duty Cycle Maximum)	40 mA
Operating Temperature Range	
Industrial (B Version)	−40°C to +85°C
Extended (T Version)	−55°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
CERDIP Package, Power Dissipation	900 mW
θ_{JA}, Thermal Impedance	76°C/W
Lead Temperature, Soldering (10 sec)	300°C
PDIP Package, Power Dissipation	470 mW
θ_{JA}, Thermal Impedance	117°C/W
Lead Temperature, Soldering (10 sec)	260°C
TSSOP Package, Power Dissipation	450 mW
θ_{JA}, Thermal Impedance	155°C/W
θ_{JC}, Thermal Impedance	50°C/W
SOIC Package, Power Dissipation	600 mW
θ_{JA}, Thermal Impedance	77°C/W
Lead Temperature, Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

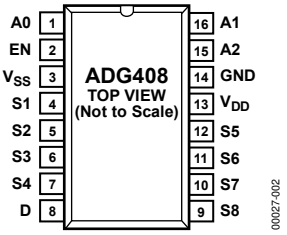


Figure 2. ADG408 Pin Configuration

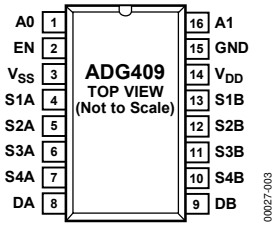


Figure 3. ADG409 Pin Configuration

Table 4. ADG408 Pin Function Descriptions

Pin No.	Mnemonic	Description
1	A0	Logic Control Input.
2	EN	Active High Digital Input. When low, the device is disabled and all switches are off. When high, Ax logic inputs determine on switches.
3	V_{SS}	Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it can be connected to ground.
4	S1	Source Terminal 1. Can be an input or an output.
5	S2	Source Terminal 2. Can be an input or an output.
6	S3	Source Terminal 3. Can be an input or an output.
7	S4	Source Terminal 4. Can be an input or an output.
8	D	Drain Terminal. Can be an input or an output.
9	S8	Source Terminal 8. Can be an input or an output.
10	S7	Source Terminal 7. Can be an input or an output.
11	S6	Source Terminal 6. Can be an input or an output.
12	S5	Source Terminal 5. Can be an input or an output.
13	V_{DD}	Most Positive Power Supply Potential.
14	GND	Ground (0 V) Reference.
15	A2	Logic Control Input.
16	A1	Logic Control Input.

Table 5. ADG409 Pin Function Descriptions

Pin No.	Mnemonic	Description
1	A0	Logic Control Input.
2	EN	Active High Digital Input. When low, the device is disabled and all switches are off. When high, Ax logic inputs determine on switches.
3	V_{SS}	Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it can be connected to ground.
4	S1A	Source Terminal 1A. Can be an input or an output.
5	S2A	Source Terminal 2A. Can be an input or an output.
6	S3A	Source Terminal 3A. Can be an input or an output.
7	S4A	Source Terminal 4A. Can be an input or an output.
8	DA	Drain Terminal A. Can be an input or an output.
9	DB	Drain Terminal B. Can be an input or an output.
10	S4B	Source Terminal 4B. Can be an input or an output.
11	S3B	Source Terminal 3B. Can be an input or an output.
12	S2B	Source Terminal 2B. Can be an input or an output.
13	S1B	Source Terminal 1B. Can be an input or an output.
14	V_{DD}	Most Positive Power Supply Potential.
15	GND	Ground (0 V) Reference.
16	A1	Logic Control Input.

Table 6. ADG408 Truth Table

A2	A1	A0	EN	On Switch
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

Table 7. ADG409 Truth Table

A1	A0	EN	On Switch Pair
X	X	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

TYPICAL PERFORMANCE CHARACTERISTICS

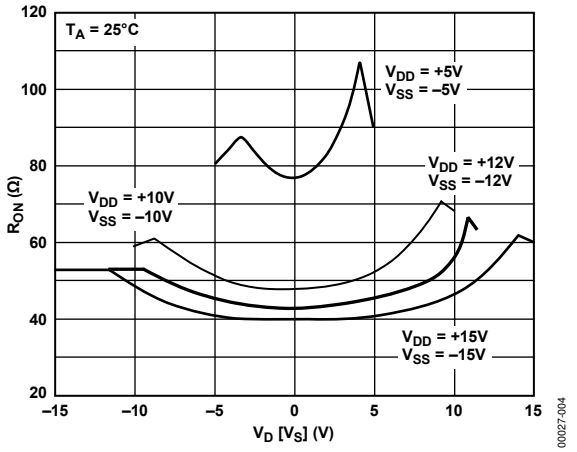


Figure 4. R_{ON} as a Function of V_D (V_S): Dual-Supply Voltage

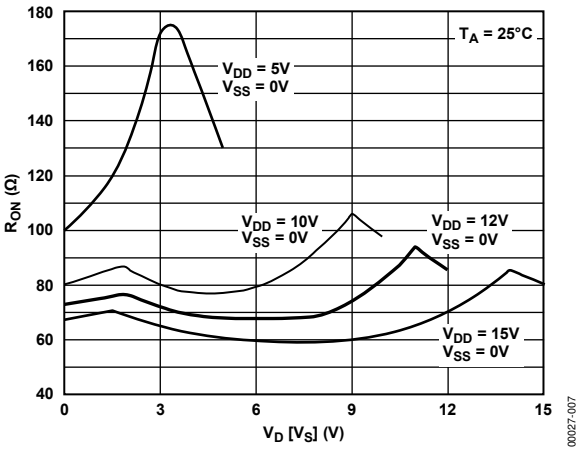


Figure 7. R_{ON} as a Function of V_D (V_S): Single-Supply Voltage

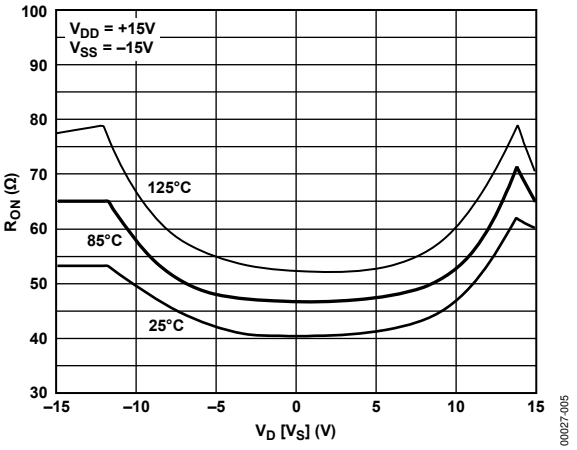


Figure 5. R_{ON} as a Function of V_D (V_S) for Different Temperatures

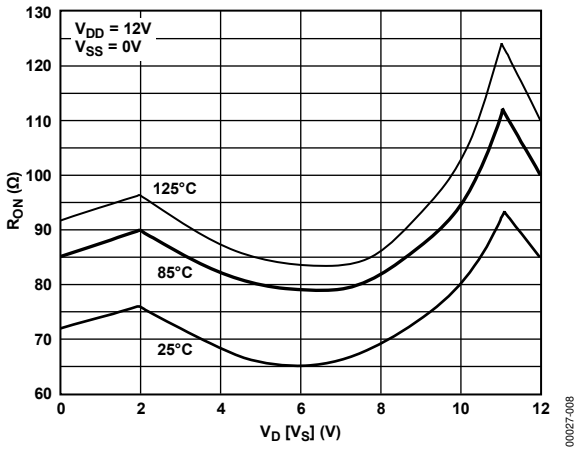


Figure 8. R_{ON} as a Function of V_D (V_S) for Different Temperature

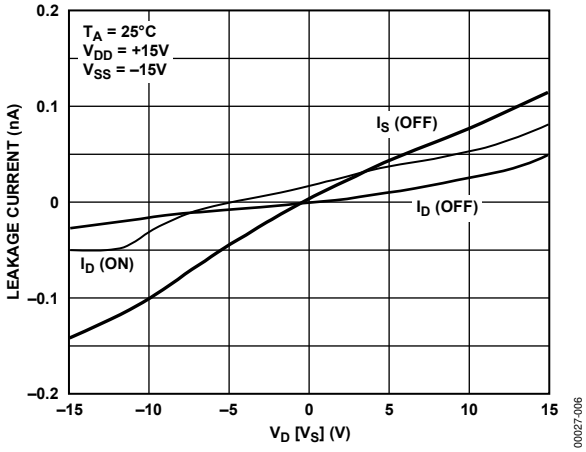


Figure 6. Leakage Currents as a Function of V_D (V_S)

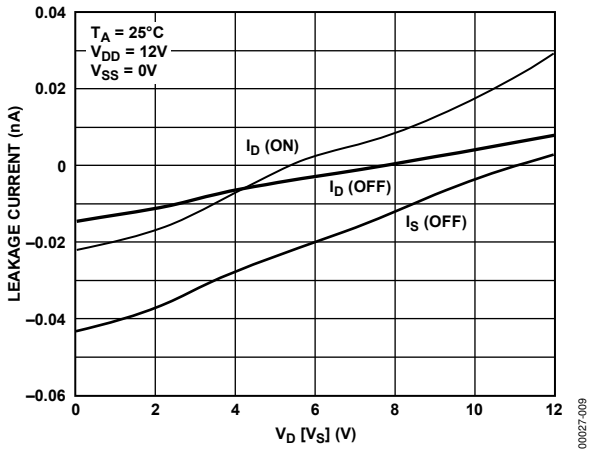


Figure 9. Leakage Currents as a Function of V_D (V_S)

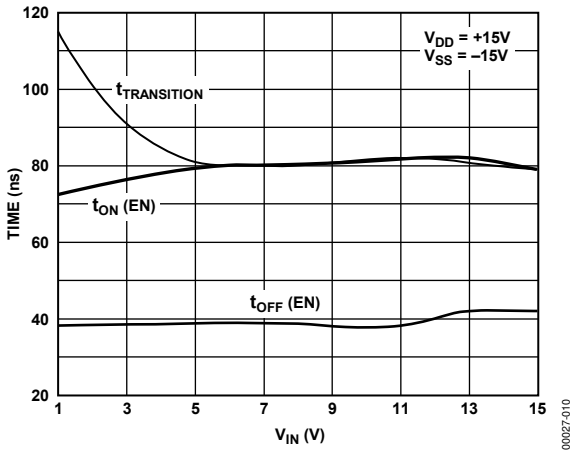


Figure 10. Switching Time vs. V_{IN} (Bipolar Supply)

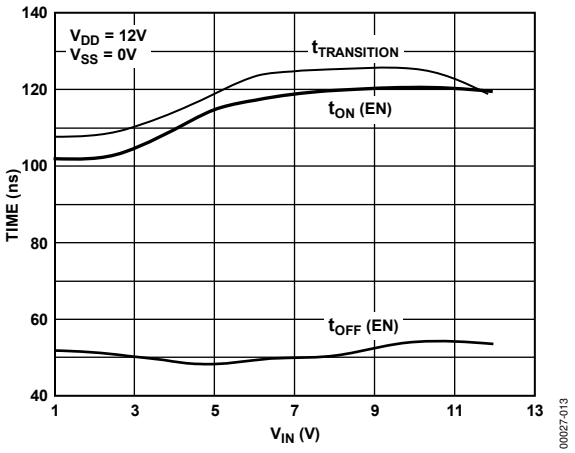


Figure 13. Switching Time vs. V_{IN} (Single Supply)

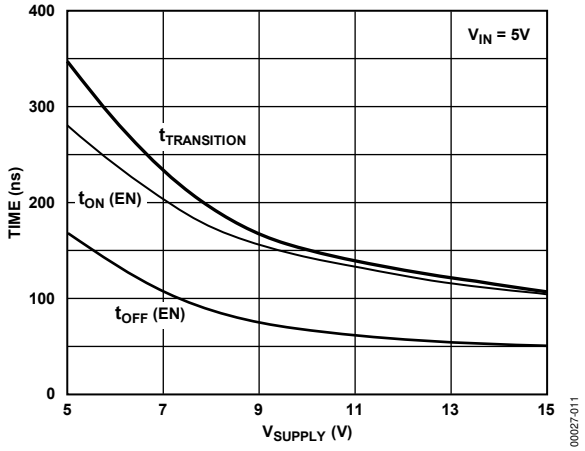


Figure 11. Switching Time vs. Single Supply

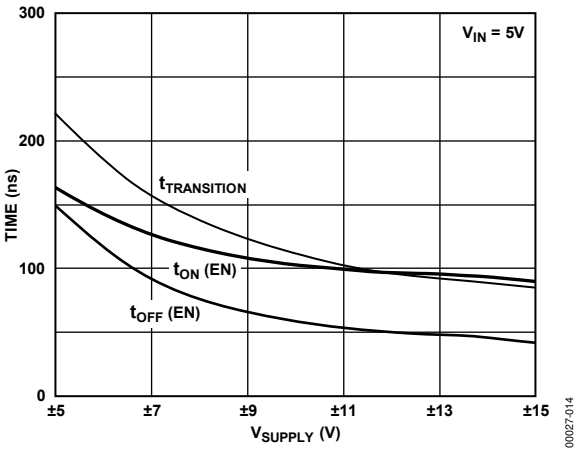


Figure 14. Switching Time vs. Bipolar Supply

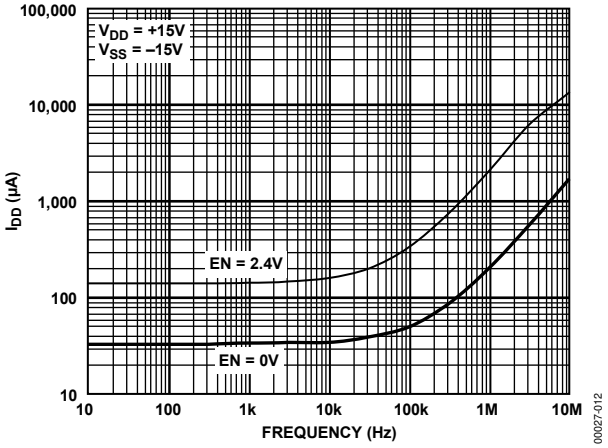


Figure 12. Positive Supply Current vs. Switching Frequency

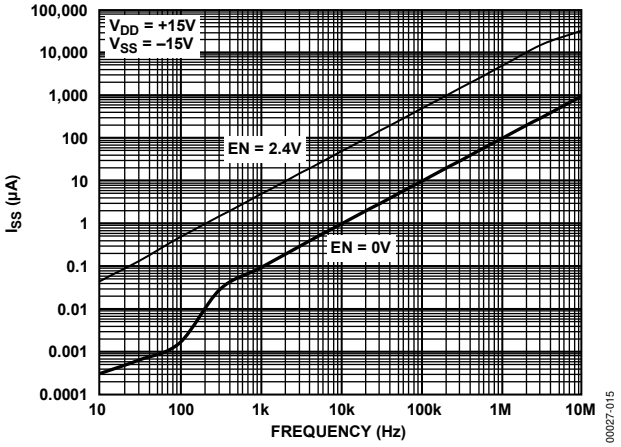


Figure 15. Negative Supply Current vs. Switching Frequency

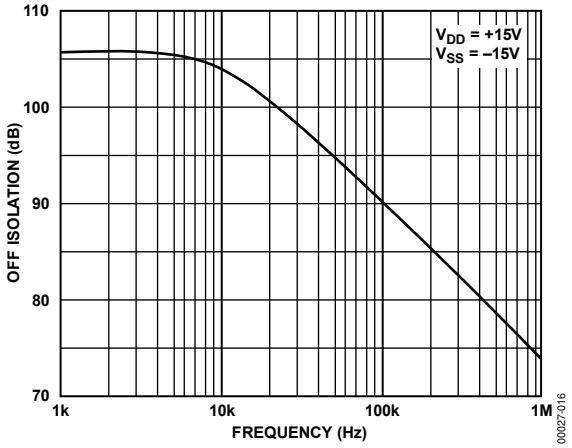


Figure 16. Off Isolation vs. Frequency

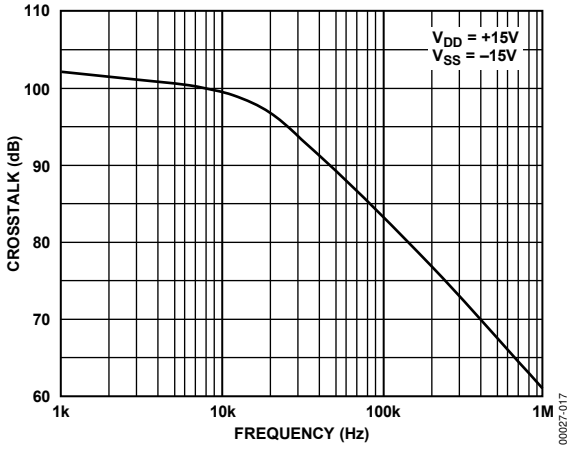


Figure 17. Crosstalk vs. Frequency

TEST CIRCUITS

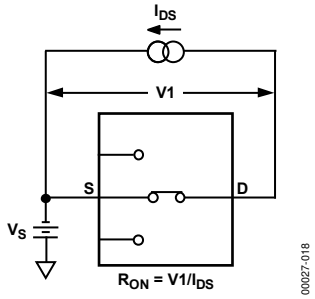


Figure 18. On Resistance

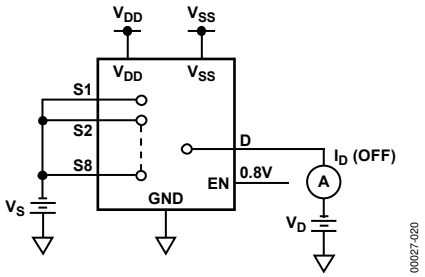


Figure 20. I_D (Off)

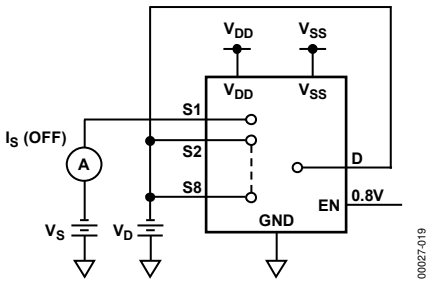


Figure 19. I_S (Off)

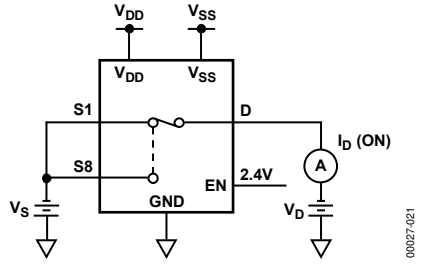


Figure 21. I_D (On)

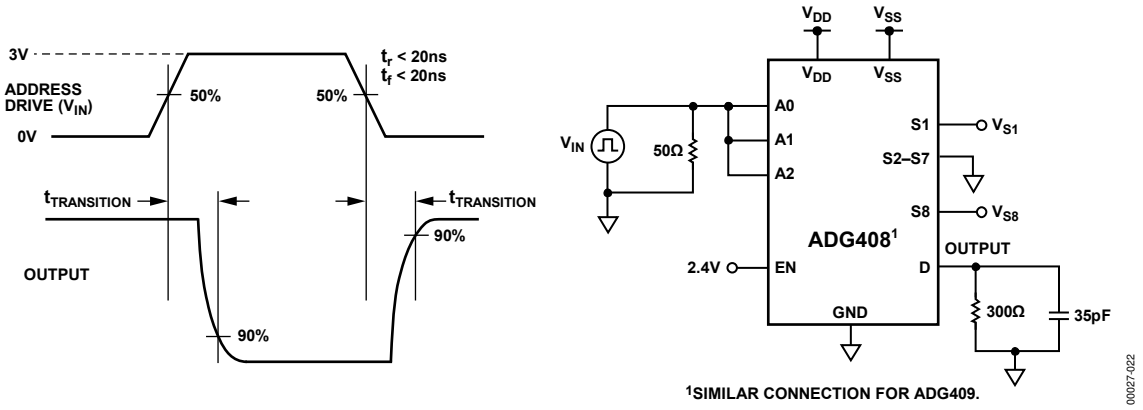


Figure 22. Switching Time of Multiplexer, $t_{TRANSITION}$

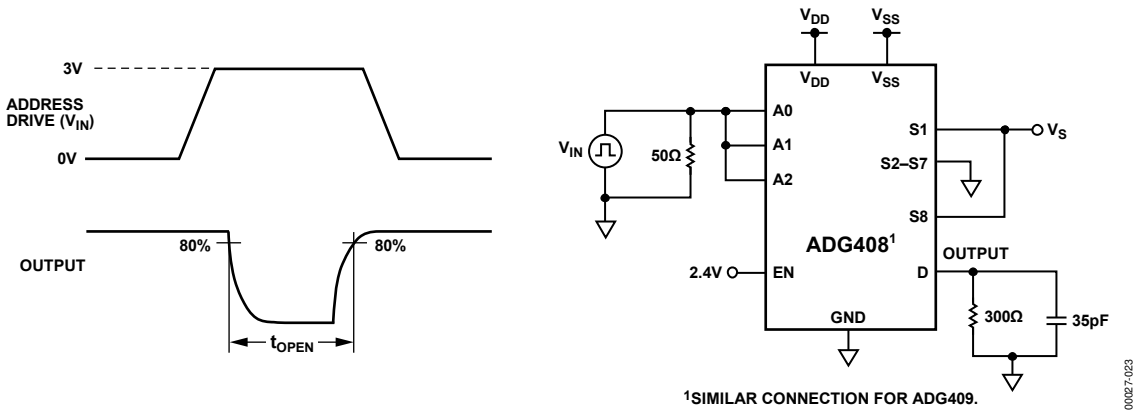


Figure 23. Break-Before-Make Delay, t_{OPEN}

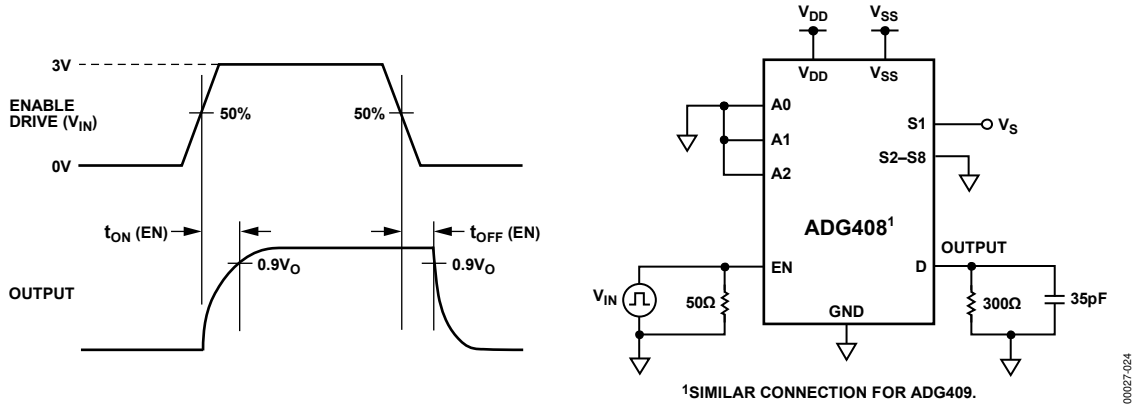


Figure 24. Enable Delay, t_{ON} (EN), t_{OFF} (EN)

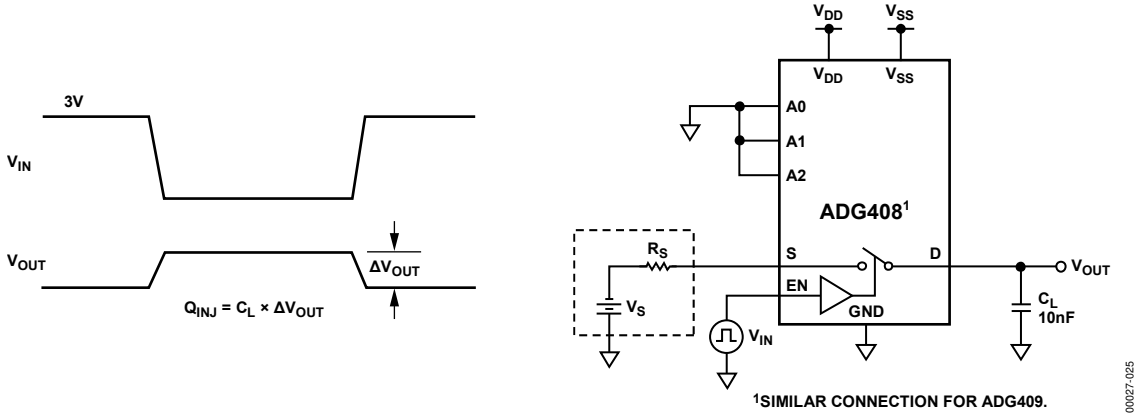


Figure 25. Charge Injection

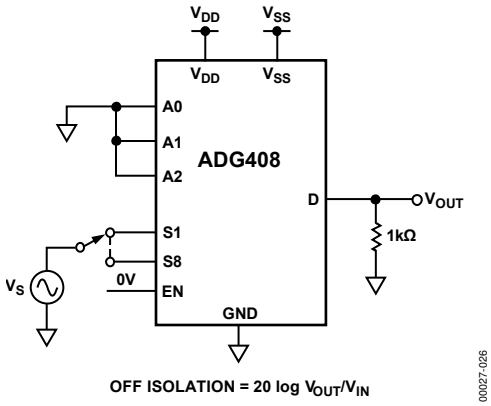


Figure 26. Off Isolation

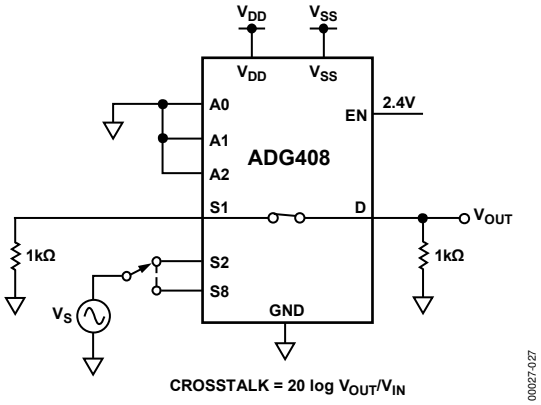


Figure 27. Channel-to-Channel Crosstalk

TERMINOLOGY

R_{ON}
Ohmic resistance between D and S.

ΔR_{ON}
Difference between the R_{ON} of any two channels.

I_S (Off)
Source leakage current when the switch is off.

I_D (Off)
Drain leakage current when the switch is off.

I_D, I_S (On)
Channel leakage current when the switch is on.

V_D (V_S)
Analog voltage on Terminal D and Terminal S.

C_S (Off)
Channel input capacitance for off condition.

C_D (Off)
Channel output capacitance for off condition.

C_D, C_S (On)
On switch capacitance.

C_{IN}
Digital input capacitance.

t_{ON} (EN)
Delay time between the 50% and 90% points of the digital input and switch on condition.

t_{OFF} (EN)
Delay time between the 50% and 90% points of the digital input and switch off condition.

$t_{TRANSITION}$
Delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

t_{OPEN}
Off time measured between the 80% point of both switches when switching from one address state to another.

V_{INL}
Maximum input voltage for Logic 0.

V_{INH}
Minimum input voltage for Logic 1.

I_{INL} (I_{INH})
Input current of the digital input.

Crosstalk
A measure of unwanted signal that is coupled through from one channel to another as a result of parasitic capacitance.

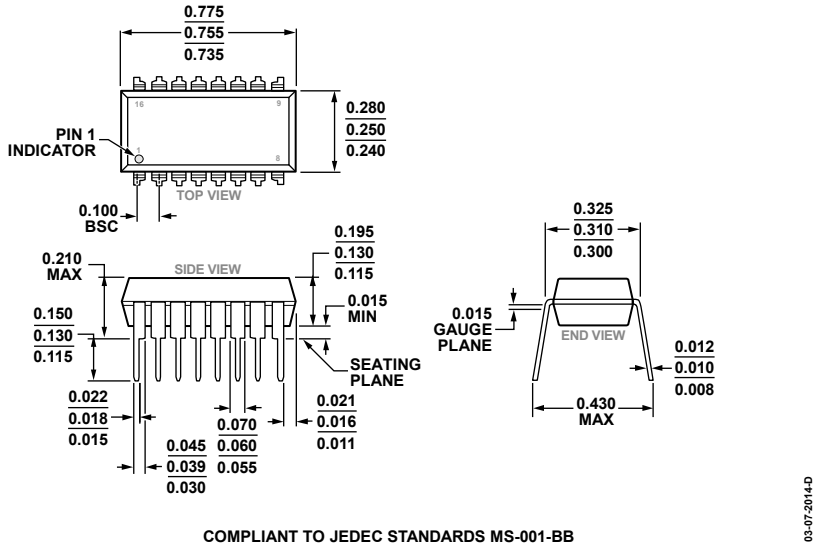
Off Isolation
A measure of unwanted signal coupling through an off channel.

Charge Injection
A measure of the glitch impulse transferred from the digital input to the analog output during switching.

I_{DD}
Positive supply current.

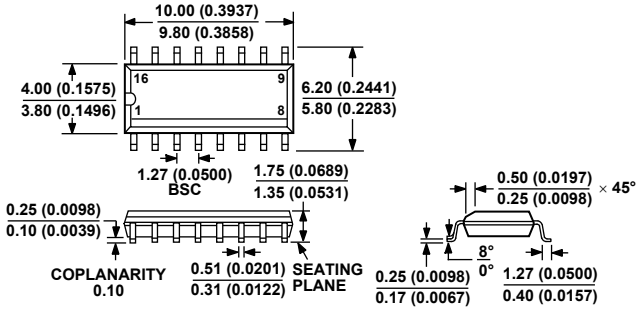
I_{SS}
Negative supply current.

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-001-BB

Figure 28. 16-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body
(N-16)
Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-012-AC

CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 29. 16-Lead Standard Small Outline Package [SOIC_N]
Narrow Body
(R-16)
Dimensions shown in millimeters and (inches)

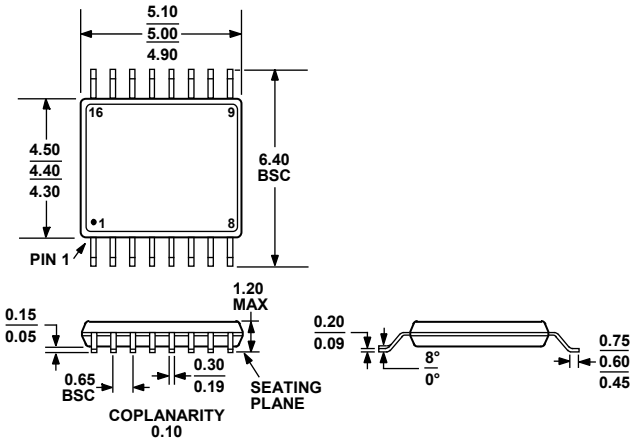


Figure 30. 16-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-16)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option
ADG408BN	−40°C to +85°C	16-Lead Plastic Dual In-Line Package [PDIP]	N-16
ADG408BNZ	−40°C to +85°C	16-Lead Plastic Dual In-Line Package [PDIP]	N-16
ADG408BR	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG408BR-REEL	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG408BR-REEL7	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG408BRU	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG408BRU-REEL	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG408BRU-REEL7	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG408BRUZ	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG408BRUZ-REEL	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG408BRUZ-REEL7	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG408BRZ	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG408BRZ-REEL	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG408BRZ-REEL7	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG408BCHIPS		DIE	
ADG409BNZ	−40°C to +85°C	16-Lead Plastic Dual In-Line Package [PDIP]	N-16
ADG409BR	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG409BR-REEL7	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG409BRUZ	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG409BRUZ-REEL7	−40°C to +85°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG409BRZ	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG409BRZ-REEL	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16
ADG409BRZ-REEL7	−40°C to +85°C	16-Lead Narrow Body Small Outline Package [SOIC_N]	R-16

[1] Z = RoHS Compliant Part